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Flexible InP based quantum dot light-emitting diodes using Ag nanowire-colorless polyimide composite electrode

Jong-Woong Kim, and Jiwan Kim

Journal of Vacuum Science & Technology B, Nanotechnology and Microelectronics: Materials, Processing, Measurement, and Phenomena **35**, 04E101 (2017); <http://doi.org/10.1116/1.4984804>

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High-resolution imaging of Li-ion migration at the interface of $\text{Li}_x\text{Ti}_5\text{O}_{12}$ and solid electrolyte in an all-solid-Li-ion battery

Ryuma Osaka, Yuki Matsushita, Kenta Kita, and Keiji Takata

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Effect of Al_2O_3 passivation layer on the stability of aluminum-indium-zinc oxide thin film transistors

Ji-In Park, Youseong Lim, Minhyung Jang, Namgyung Hwang, and Moonsuk Yi

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Current-driven interface magnetic transition in complex oxide heterostructure

F. Fang, H. Zhai, X. Ma, Y. W. Yin, Qi Li more...

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Creating and probing quantum dot molecules with the scanning tunneling microscope

Yi Pan, Kiyoshi Kanisawa, and Stefan Fölsch

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Toru Akiyama, Go Yoshimura, Kohji Nakamura, and Tomonori Ito

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Defect density reduction in core layer of ZnTe electro-optical waveguide by low lattice mismatched interfaces

Wei-Che Sun, Taizo Nakusu, Keisuke Odaka, Masakazu Kobayashi, and Toshiaki Asahi

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Interfacial reactions at Fe/topological insulator spin contacts

Sarmita Majumder, Karalee Jarvis, Sanjay K. Banerjee, and Karen L. Kavanagh

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Nucleation of Cu₂Te layer by a closed space sublimation method toward the growth of Te based chalcopyrite

Yohei Sakurakawa, Aya Urano, and Masakazu Kobayashi

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Zhaoxiang Qi, and Gary M. Koenig Jr.

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Impact of ultrathin Al₂O₃ interlayers on resistive switching in TiO_x thin films deposited by atomic layer deposition

Weixia Liu, Leiwen Gao, Kewei Xu, and Fei Ma

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Conduction and valence band offsets of LaAl₂O₃ with (-201) β-Ga₂O₃

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Barium strontium oxide functionalized carbon nanotubes thin film thermionic emitter with superior thermionic emission capability

Feng Jin, and Allyn Beaver

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Investigation of low-fluence hydrogen implantation-induced cracking in B doped $\text{Si}_{0.70}\text{Ge}_{0.30}$

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Chemical mechanical polishing of $\text{Ge}_2\text{Sb}_2\text{Te}_5$ in alkaline slurry

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Effect of various Fe-doped AlGaN buffer layer of AlGaN/GaN HEMTs on Si substrate

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High-performance electro-optical characteristics of organic light-emitting diode using dipyrrazino[2,3-f:2',3'-h] quinoxaline-2,3

Hong-Gyu Park, and Sang-Geon Park

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Photocatalytic performance of TiVO_x/TiO₂ thin films prepared by bipolar pulsed magnetron sputter deposition

Ko-Wei Weng, and Sheng Han

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Substrate preparation effects on defect density in molecular beam epitaxial growth of CdTe on CdTe (100) and (211)B

George L. Burton, David R. Diercks, Craig L. Perkins, Teresa M. Barnes, Olanrewaju S. Ogedengbe more...

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Enhancing the dry etch resistance of polymethyl methacrylate patterned with electron beam lithography

Daniel J. Carbaugh, Sneha G. Pandya, Jason T. Wright, Savas Kaya, and Faiz Rahman

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Nanoimprint lithography tone reversal process using poly(methyl methacrylate) and hydrogen silsesquioxane

Long Chang, and Dmitri Litvinov

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Electron field emission from SiC nanopillars produced by using nanosphere lithography

Damla Yeşilpınar, and Cem Çelebi

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Carbon monolith scaffolding for high volumetric capacity silicon Li-ion battery anodes

Lawrence K. Barrett, Juichin Fan, Kevin Laughlin, Sterling Baird, John N. Harb more...

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Effect of polytypism on the long and short range crystal structure of InAs nanostructures: An EXAFS and Raman spectroscopy study

Suparna Pal, Parasmani Rajput, Shreyashkar Dev Singh, Vasant G. Sathe, and Shambhu Nath Jha

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Evolution of photoelectron spectra at thermal reduction of graphene oxide

Viktor P. Afanas'ev, Grigorii S. Bocharov, Alexander V. Eletskii, Olga Yu. Ridzel, Pavel S. Kaplya more...

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Monte Carlo simulations of secondary electron emission due to ion beam milling

Kyle Mahady, Shida Tan, Yuval Greenzweig, Richard Livengood, Amir Raveh more...

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Miniaturized magnet-less RF electron trap. I. Modeling and analysis

Aram H. Markosyan, Scott R. Green, Shiyang Deng, Yogesh B. Gianchandani, and Mark J. Kushner

Journal of Vacuum Science & Technology B, Nanotechnology and Microelectronics: Materials, Processing, Measurement, and Phenomena **35**, 042001 (2017); <http://doi.org/10.1116/1.4984751>

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Miniaturized magnet-less RF electron trap. II. Experimental verification

Shiyang Deng, Scott R. Green, Aram H. Markosyan, Mark J. Kushner, and Yogesh B. Gianchandani

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High-etch rate processes for performing deep, highly anisotropic etches in silicon carbide using inductively coupled plasma etching

Mehmet Ozgur, and Michael Huff

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Detection of ammonia at low concentrations (0.1–2 ppm) with ZnO nanorod-functionalized AlGaN/GaN high electron mobility transistors

Sunwoo Jung, Kwang Hyeon Baik, Fan Ren, Stephen J. Pearton, and Soohwan Jang

Journal of Vacuum Science & Technology B, Nanotechnology and Microelectronics: Materials, Processing, Measurement, and Phenomena **35**, 042201 (2017); <http://doi.org/10.1116/1.4989370>
